



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





# IR Emitter and Detector Product Data Sheet

LTE-3276

Spec No.: DS50-2008-0044

Effective Date: 08/17/2012

Revision: A

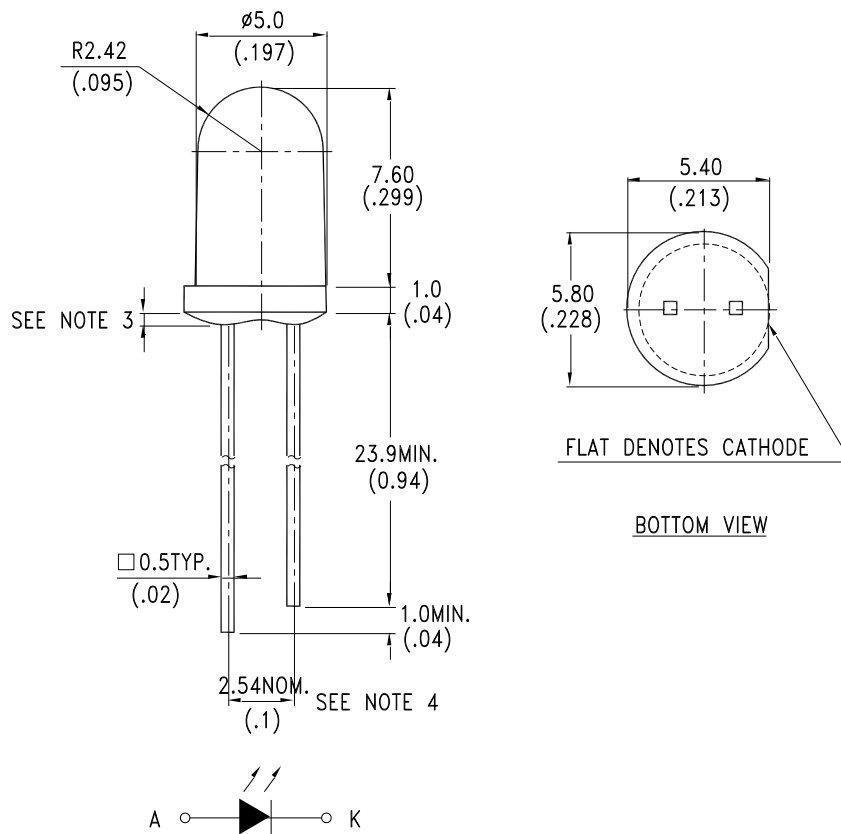
**LITE-ON DCC**

**RELEASE**

BNS-OD-FC001/A4

**FEATURES**

- \* HIGH SPEED
- \* HIGH POWER
- \* AVAILABLE FOR PULSE OPERATING
- \* CLEAR TRANSPARENT COLOR PACKAGE

**PACKAGE DIMENSIONS****NOTES:**

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.25$ mm (.010") unless otherwise noted.
3. Protruded resin under flange is 1.5mm (.059") max.
4. Lead spacing is measured where the leads emerge from the package.
5. Specifications are subject to change without notice.



# LITE-ON TECHNOLOGY CORPORATION

Property of Lite-On Only

## ABSOLUTE MAXIMUM RATINGS AT TA=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation	200	mW
Peak Forward Current (300pps, 10 $\mu$ s pulse)	1	A
Continuous Forward Current	100	mA
Reverse Voltage	5	V
Operating Temperature Range	-40°C to + 85°C	
Storage Temperature Range	-40°C to + 85°C	
Lead Soldering Temperature [1.6mm(.063") From Body]	260°C for 6 Seconds	

## ELECTRICAL / OPTICAL CHARACTERISTICS AT TA=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Aperture Radiant Incidence	E <sub>e</sub>	1.3	1.7	-	mW/cm <sup>2</sup>	I <sub>F</sub> = 20mA
Radiant Intensity	I <sub>E</sub>	9.75	12.75	-	mW/sr	I <sub>F</sub> = 20mA
Radiant Intensity	I <sub>E</sub>	24	32	-	mW/sr	I <sub>F</sub> = 50mA
Peak Emission Wavelength	$\lambda_P$	-	850	-	nm	I <sub>F</sub> = 50mA
Spectral Line Half-Width	$\Delta \lambda$	-	40	-	nm	I <sub>F</sub> = 50mA
Forward Voltage	V <sub>F</sub>	-	1.49	1.80	V	I <sub>F</sub> = 50mA
Forward Voltage	V <sub>F</sub>	-	1.83	2.3	V	I <sub>F</sub> = 200mA
Reverse Voltage	V <sub>R</sub>	5	-	-	V	I <sub>R</sub> = 10 $\mu$ A
Viewing Angle (See FIG.6)	2 $\theta_{1/2}$	-	50	-	deg.	I <sub>F</sub> = 20mA

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

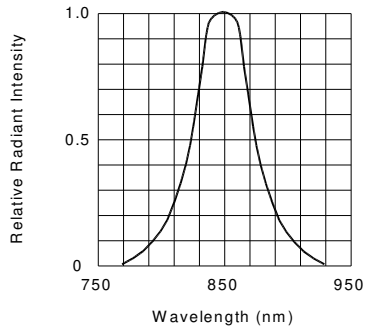


FIG.1 SPECTRAL DISTRIBUTION

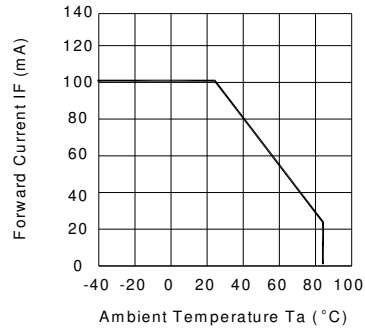


FIG.2 FORWARD CURRENT VS. AMBIENT TEMPERATURE

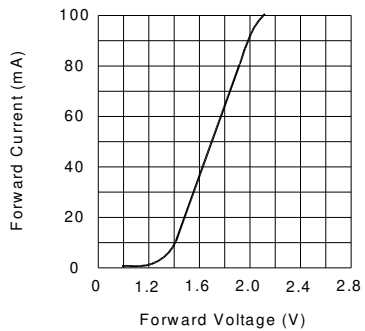


FIG.3 FORWARD CURRENT VS. FORWARD VOLTAGE

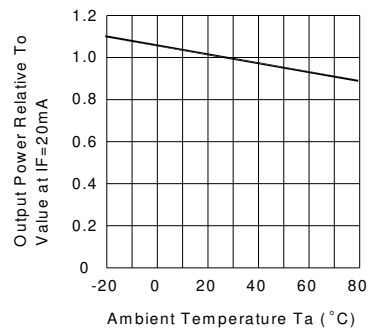


FIG.4 RELATIVE RADIANT INTENSITY VS. AMBIENT TEMPERATURE

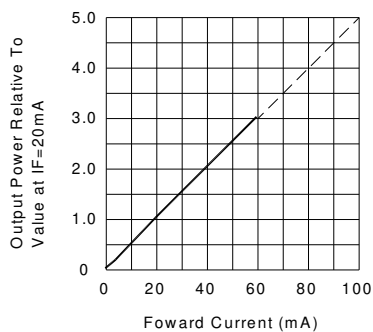


FIG.5 RELATIVE RADIANT INTENSITY VS. FORWARD CURRENT

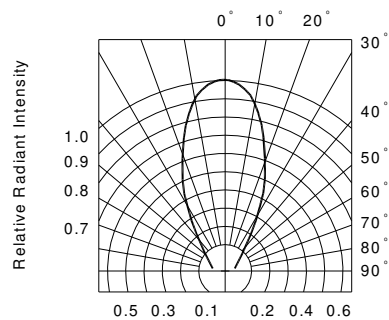


FIG.6 RADIATION DIAGRAM